TAIWAN SEMICONDUCTOR

The Smartest Choice

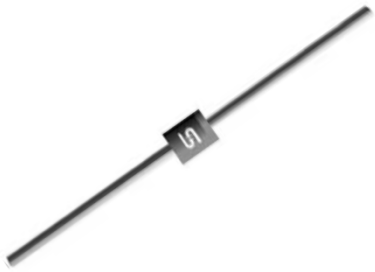
FR301G - FR307G

3.0AMPS Glass Passivated Fast Recovery Rectifiers

DO-201AD

Features

- ✧ Glass passivated chip junction
- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode



Pb-Free

RoHS COMPLIANT

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode end
- ✧ High temperature soldering guaranteed: 260℃/10s
- ✧ Weight: 1.2 grams

Ordering Information (example)

Part No.	Package	Packing	INNER TAPE	Packing code	Packing code (Green)
FR301G	DO-201AD	500 / AMMO box	52mm	A0	A0G

Maximum Ratings and Electrical Characteristics

Rating at 25 ℃ ambient temperature unless otherwise specified.

Parameter	Symbol	FR 301G	FR 302G	FR 303G	FR 304G	FR 305G	FR 306G	FR 307G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	3							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	125							A
Maximum Instantaneous Forward Voltage (Note 1) @ 3 A	V_F	1.3							V
Maximum DC Reverse Current at @ T_A=25 ℃	I_R	5							uA
Rated DC Blocking Voltage @ T_A=125 ℃		100							uA
Maximum Reverse Recovery Time (Note 2)	Trr	150				250	500		nS
Typical Junction Capacitance (Note 3)	Cj	30							pF
Typical Thermal Resistance	$R_{\theta JA}$	35							^{O}C/W
Operating Temperature Range	T_J	- 55 to + 150							^{O}C
Storage Temperature Range	T_{STG}	- 55 to + 150							^{O}C

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

TAIWAN SEMICONDUCTOR
The Smartest Choice

RATINGS AND CHARACTERISTIC CURVES (FR301G THRU FR307G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

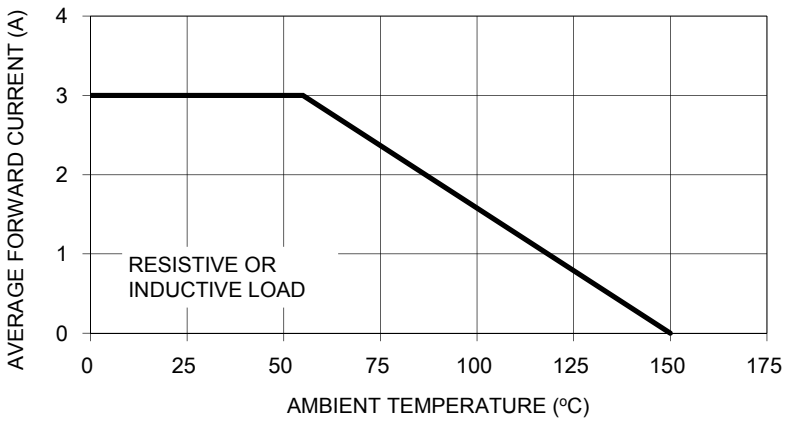


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

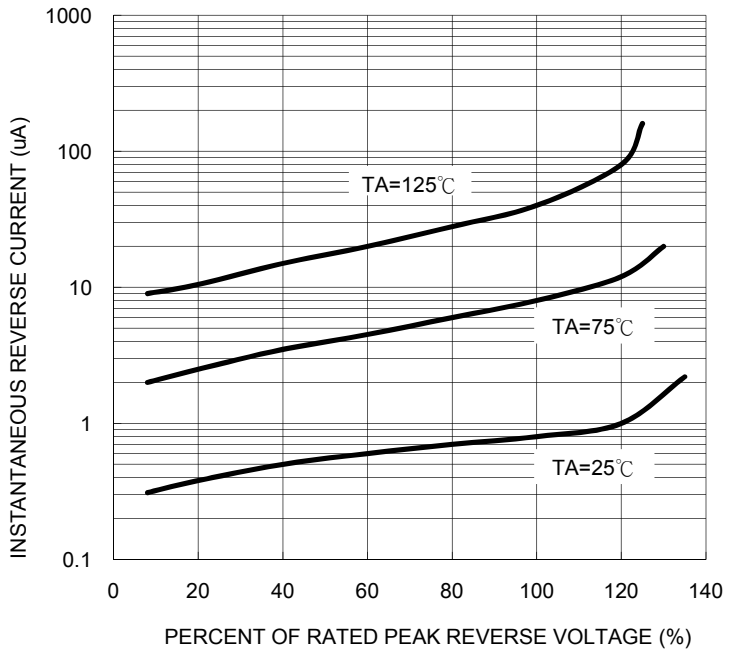


FIG. 3- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

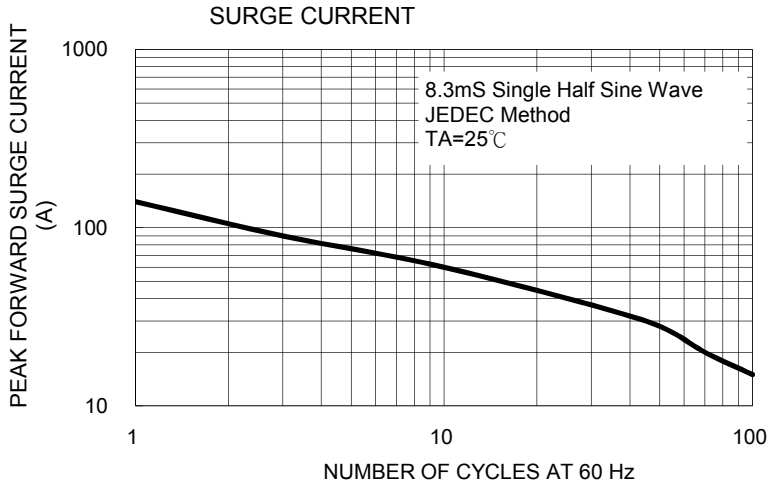


FIG. 5- TYPICAL FORWARD CHARACTERISTICS

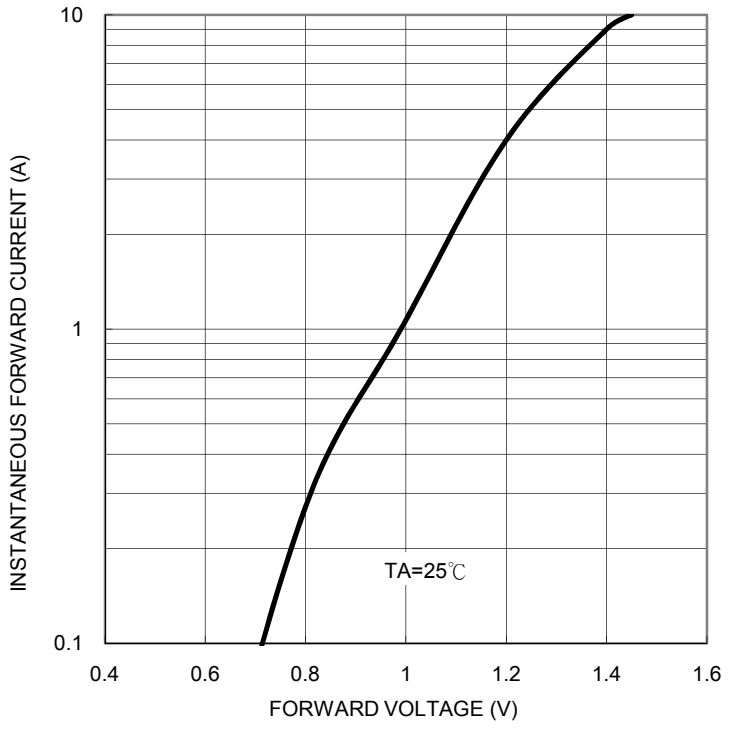


FIG. 4- TYPICAL JUNCTION CAPACITANCE

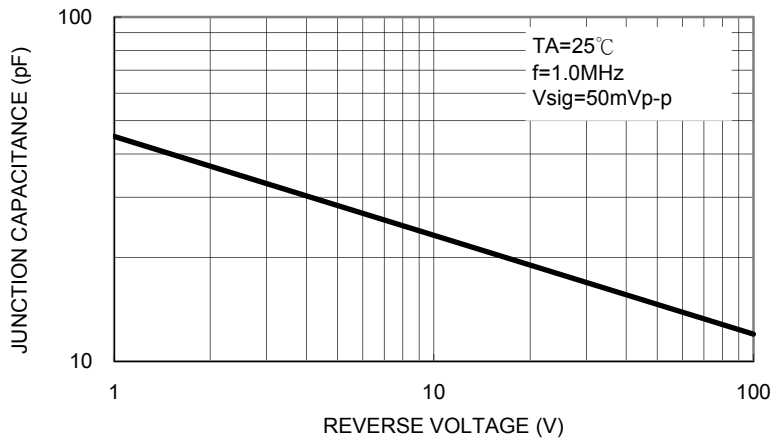
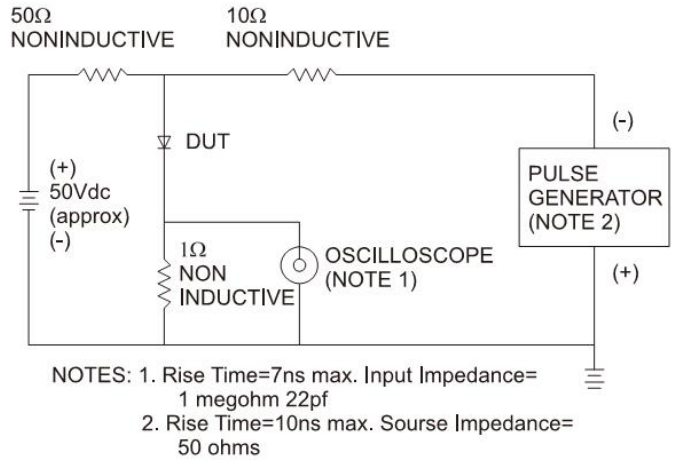
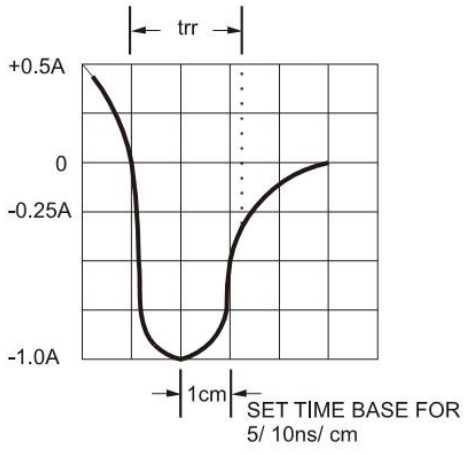


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



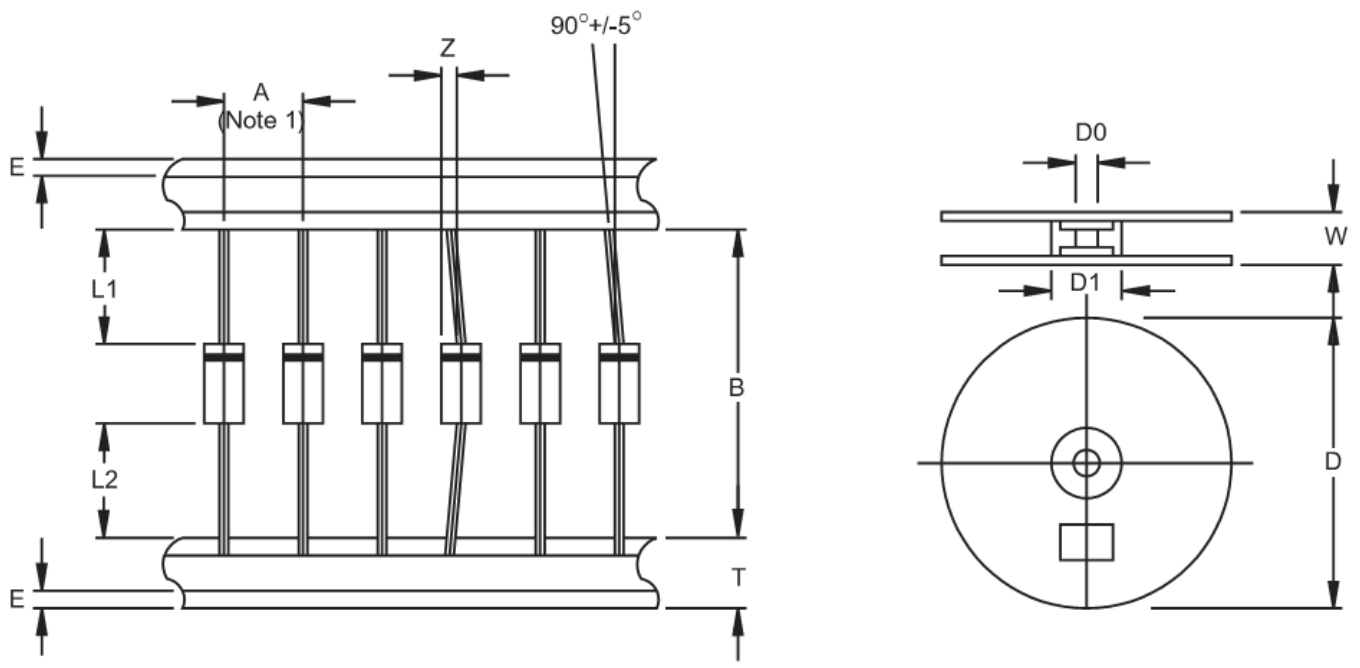


Ordering information

Part No.	Package	Packing	INNER TAPE	Packing code	Packing code (Green)
FR30xG (Note)	DO-201AD	500 / AMMO box	52mm	A0	A0G
	DO-201AD	1.25K / 13" Reel	52mm	R0	R0G
	DO-201AD	500 / Bulk packing		B0	B0G
	DO-201AD	Forming		X0	X0G

Note: "x" is Device Code from "1" thru "7".

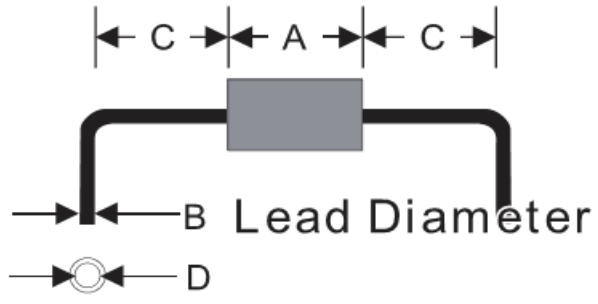
AXIAL LEAD TAPING SPECIFICATIONS



Outline	A	B	Z	T	E	L1-L2	D	D1	D0	W
	±0.5	±1.5	MAX	±0.4	MAX	MAX		±0.3	±0.4	±1.0
DO-201AD	10	52.4	1.2	6	0.8	1	330	85.7	16.6	76

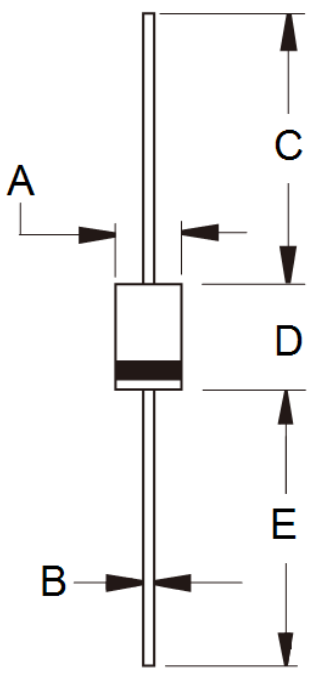
Unit (mm)

Suggested Mounting Hole Rule



Symbol	Unit(mm)
A	9.0
B	1.2
C	4.0
D	1.6

Dimensions



DIM.	Unit(mm)		Unit(inch)	
	Min	Max	Min	Max
A	5.00	5.60	0.197	0.220
B	1.20	1.30	0.048	0.052
C	25.40	-	1.000	-
D	8.50	9.50	0.335	0.375
E	25.40	-	1.000	-

Marking Diagram



P/N	= Specific Device Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code